NSN 5961-01-049-8368

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-049-8368 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Field effect **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 60.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source and 60.0 reverse gate to source voltage **Current Rating Per Characteristic:** 20.00 milliamperes drain current and 10.00 milliamperes gate current **Power Rating Per Characteristic:** 200.0 milliwatts total device dissipation **Test Data Document:** 77327-40704 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**